

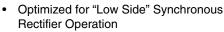


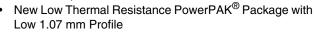
N-Channel 30-V (D-S) MOSFET

| PRODUCT SUMMARY | | | | | |
|---------------------|---|--------------------|-----------------------|--|--|
| V _{DS} (V) | $R_{DS(on)}(\Omega)$ | I _D (A) | Q _g (Typ.) | | |
| 30 | $0.0042 \text{ at V}_{GS} = 10 \text{ V}$ | 23 | 30.5 | | |
| | 0.0059 at $V_{GS} = 4.5 \text{ V}$ | 20 | 30.5 | | |

FEATURES

- · Halogen-free available
- TrenchFET® Power MOSFET

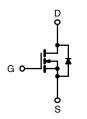




100 % R_q Tested



- DC/DC Converters
- Synchronous Rectifiers



PowerPAK SO-8

Bottom View Ordering Information: Si7358ADP-T1-E3 (Lead (Pb)-free)

Si7358ADP-T1-GE3 (Lead (Pb)-free and Halogen-free)

| ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted | | | | | | |
|---|------------------------|-----------------------------------|-------------|--------------|------|--|
| Parameter | | Symbol | 10 s | Steady State | Unit | |
| Drain-Source Voltage | | V_{DS} | 30 | | V | |
| Gate-Source Voltage | | V_{GS} | ± 20 | | V | |
| Continuous Drain Current (T _{.1} = 150 °C) ^a | T _A = 25 °C | I _D | 23 | 14 | | |
| Continuous Diain Current (1) = 130 C) | T _A = 70 °C | | 18 | 11 | | |
| Pulsed Drain Current (10 μs Pulse Width) | | I _{DM} | 60 | | Α | |
| Continuous Source Current (Diode Conduction) ^a | | I _S | 4.5 | 1.6 | | |
| Avalanche Current | L = 0.1 mH | I _{AS} | 50 | | | |
| Maximum Power Dissipation ^a | T _A = 25 °C | P _D | 5.4 | 1.9 | W | |
| waximum Power Dissipation | T _A = 70 °C | | 3.4 | 1.2 | VV | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 to 150 | | °C | |
| Soldering Recommendations (Peak Temperature) ^{b, c} | | | 260 | | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|--------------|-------------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Manian and hundring to Ambient | t ≤ 10 s | R _{thJA} | 18 | 23 | °C/W |
| Maximum Junction-to-Ambient ^a | Steady State | | 50 | 65 | |
| Maximum Junction-to-Case (Drain) | Steady State | R_{thJC} | 1.0 | 1.5 | |

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Vishay Siliconix



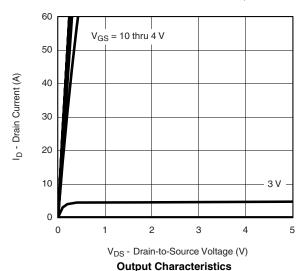
| SPECIFICATIONS T _J = 25 °C, unless otherwise noted | | | | | | | |
|--|---------------------|--|------|--------|--------|------|--|
| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit | |
| Static | | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | 1.0 | | 3.0 | ٧ | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ | | | ± 100 | nA | |
| Zero Gate Voltage Drain Current | 1 | $V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$ | | | 1 | μΑ | |
| | I _{DSS} | $V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$ | | | 5 | | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$ | 30 | | | Α | |
| Drain-Source On-State Resistance ^a | D | V _{GS} = 10 V, I _D = 23 A | | 0.0032 | 0.0042 | 0 | |
| | R _{DS(on)} | $V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$ | | 0.0045 | 0.0059 | Ω | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = 15 V, I _D = 23 A | | 90 | | S | |
| Diode Forward Voltage ^a | V_{SD} | I _S = 4.5 A, V _{GS} = 0 V | | 0.75 | 1.1 | V | |
| Dynamic ^b | | | | | | | |
| Input Capacitance | C _{iss} | | | 4650 | | pF | |
| Output Capacitance | C _{oss} | $V_{DS} = 15 \text{ V}, V_{SS} = 0 \text{ V}, f = 1 \text{ kHz}$ | | 880 | | | |
| Reverse Transfer Capacitance | C _{rss} | | | 390 | | | |
| Total Gate Charge | Q_g | | | 30.5 | 40 | | |
| Gate-Source Charge | Q _{gs} | $V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 23 \text{ A}$ | | 12.5 | | nC | |
| Gate-Drain Charge | Q_{gd} | | | 10 | | | |
| Gate Resistance | R_g | | 0.5 | 1.0 | 1.5 | Ω | |
| Turn-On Delay Time | t _{d(on)} | | | 21 | 35 | | |
| Rise Time | t _r | V_{DD} = 15 V, R_L = 15 Ω | | 10 | 20 | ns | |
| Turn-Off Delay Time | t _{d(off)} | $I_D\cong$ 1 A, V_{GEN} = 10 V, R_G = 6 Ω | | 83 | 130 | | |
| Fall Time | t _f | | | 27 | 45 | | |
| Source-Drain Reverse Recovery Time | t _{rr} | I _F = 2.9 A, di/dt = 100 A/μs | | 50 | 80 | | |

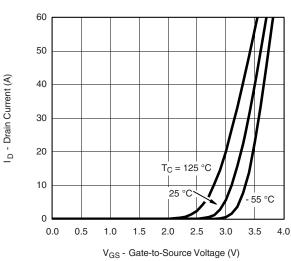
Notes:

- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





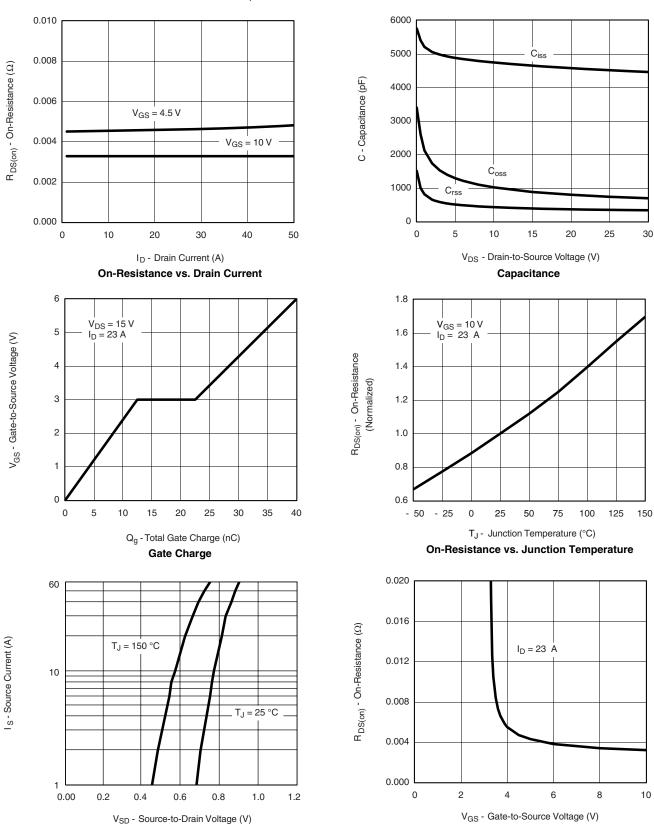
Transfer Characteristics







TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



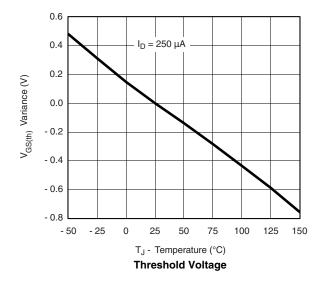
Source-Drain Diode Forward Voltage

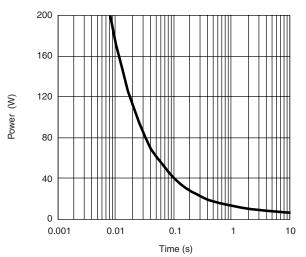
On-Resistance vs. Gate-to-Source Voltage

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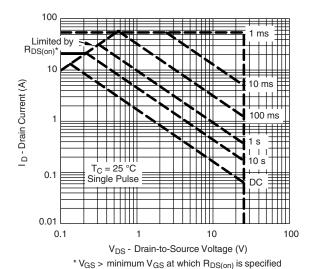
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

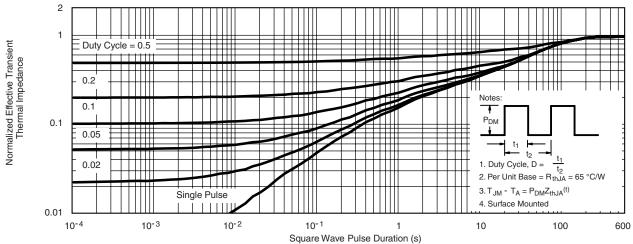




Single Pulse Power, Junction-to-Ambient



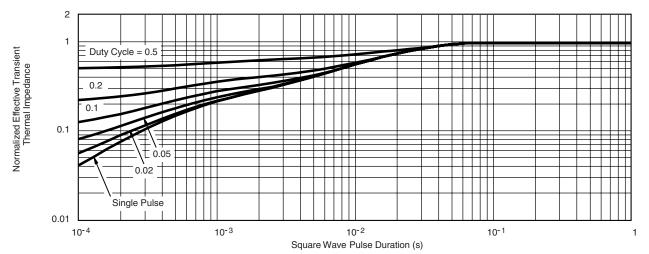
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?73161.

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